

UNR1121/1122/1123/1124/112X/112Y**(UN1121/1122/1123/1124/112X/112Y)**

Silicon PNP epitaxial planar transistor

For digital circuits

■ Features

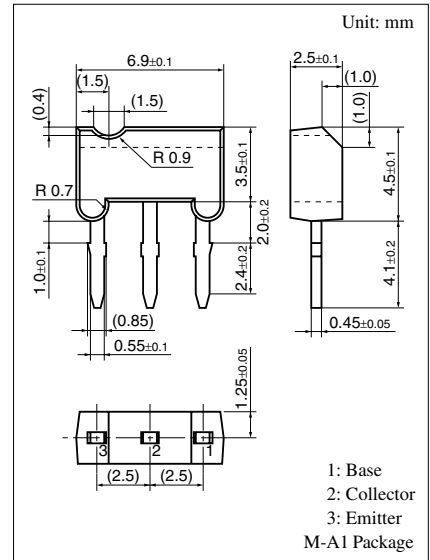
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board.

■ Resistance by Part Number

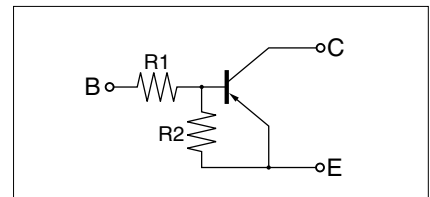
	(R ₁)	(R ₂)
• UNR1121	2.2kΩ	2.2kΩ
• UNR1122	4.7kΩ	4.7kΩ
• UNR1123	10kΩ	10kΩ
• UNR1124	2.2kΩ	10kΩ
• UNR112X	0.27kΩ	5kΩ
• UNR112Y	3.1kΩ	4.6kΩ

■ Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	-50	V
Collector to emitter voltage	V _{CEO}	-50	V
Collector current	I _C	-500	mA
Total power dissipation	P _T	600	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



Internal Connection

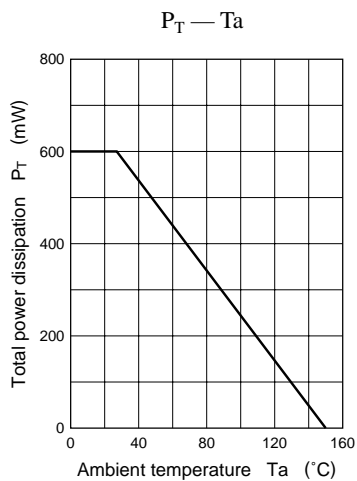


Note) The part numbers in the parenthesis show conventional part number.

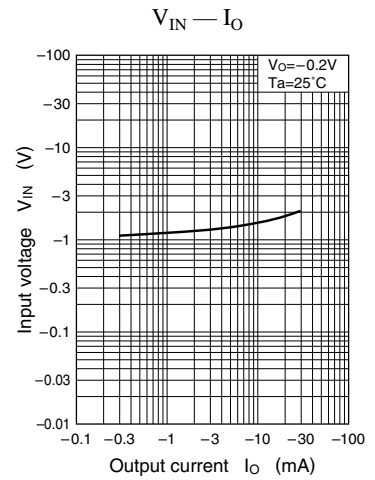
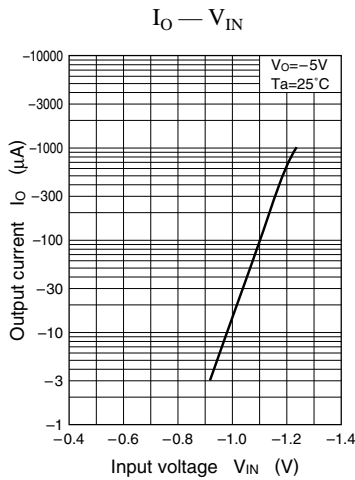
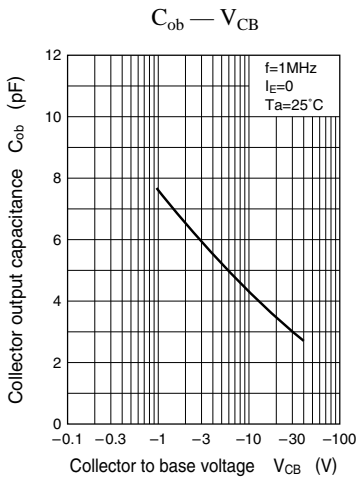
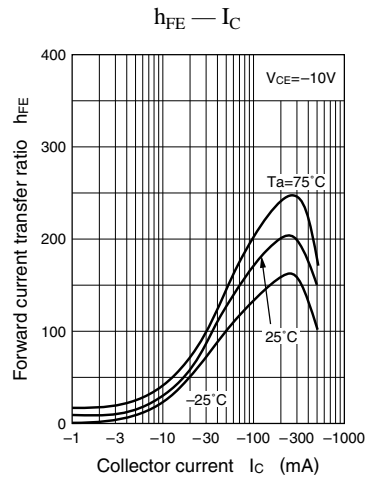
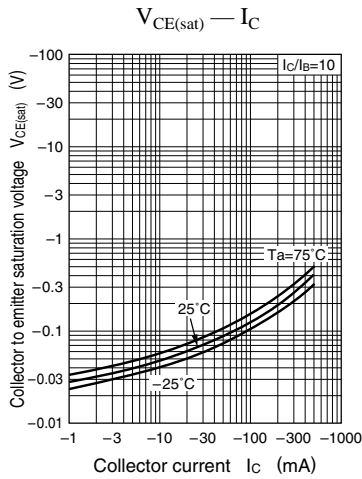
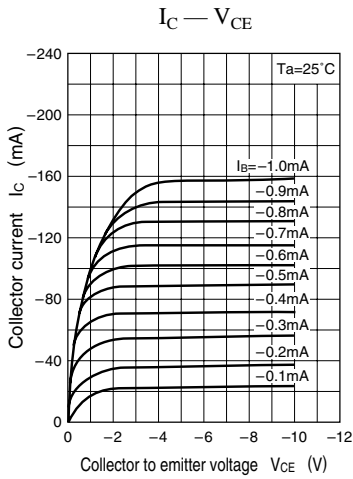
■ Electrical Characteristics (Ta=25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit	
Collector cutoff current		I_{CBO}	$V_{CB} = -50V, I_E = 0$			-1	μA	
	UNR112X	I_{CBO}	$V_{CB} = -50V, I_E = 0$			-0.1		
Collector cutoff current		I_{CEO}	$V_{CE} = -50V, I_B = 0$			-1	μA	
	UNR112X	I_{CEO}	$V_{CE} = -50V, I_B = 0$			-0.5		
Emitter cutoff current	UNR1121	I_{EBO}	$V_{EB} = -6V, I_C = 0$			-5	mA	
	UNR1122/112X/112Y					-2		
	UNR1123/1124					-1		
Collector to base voltage		V_{CBO}	$I_C = -10\mu A, I_E = 0$	-50			V	
Forward current transfer ratio	UNR1121	h_{FE}	$V_{CE} = -10V, I_C = -100mA$	40				
	UNR1122/112Y			50				
	UNR1123/1124			60				
	UNR112X			20				
Collector to emitter saturation voltage		$V_{CE(sat)}$	$I_C = -100mA, I_B = -5mA$			-0.25	V	
		UNR112X	$V_{CE(sat)}$	$I_C = -10mA, I_B = -0.3mA$				-0.25
		UNR112Y	$V_{CE(sat)}$	$I_C = -50mA, I_B = -5mA$				-0.15
Output voltage high level		V_{OH}	$V_{CC} = -5V, V_B = -0.5V, R_L = 500\Omega$	-4.9			V	
Output voltage low level		V_{OL}	$V_{CC} = -5V, V_B = -3.5V, R_L = 500\Omega$			-0.2	V	
Transition frequency		f_T	$V_{CB} = -10V, I_E = 50mA, f = 200MHz$		200		MHz	
Input resistance	UNR1121	R_1		(-30%)	2.2	(+30%)	k Ω	
	UNR1122				4.7			
	UNR1123				10			
	UNR112X				0.27			
	UNR112Y				3.1			
Resistance ratio		R_1/R_2			0.8	1.0	1.2	
					UNR1124		0.22	
					UNR112X		0.054	
					UNR112Y		0.67	

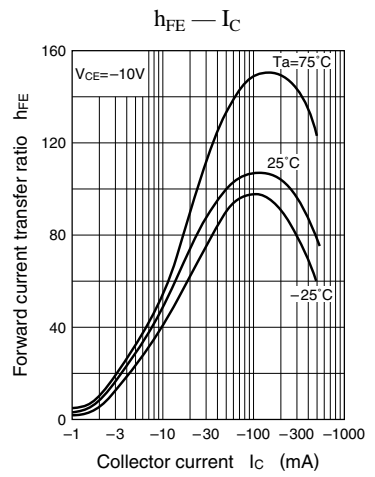
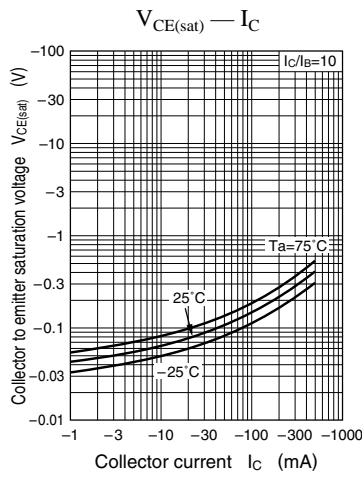
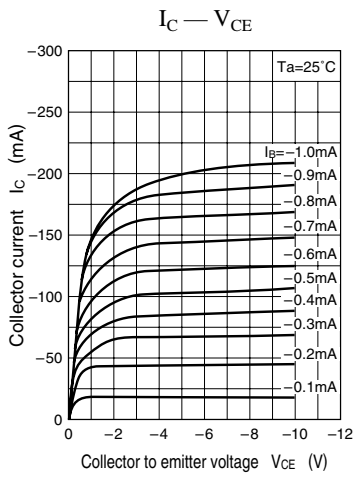
Common characteristics chart

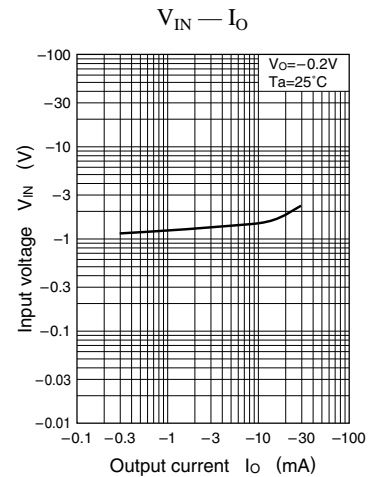
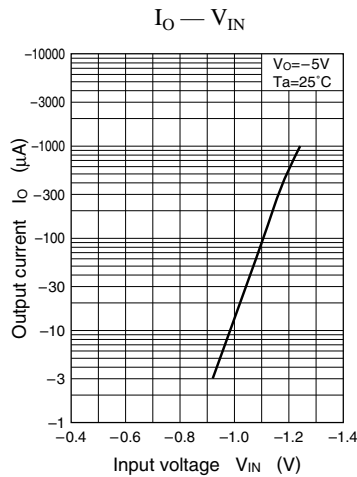
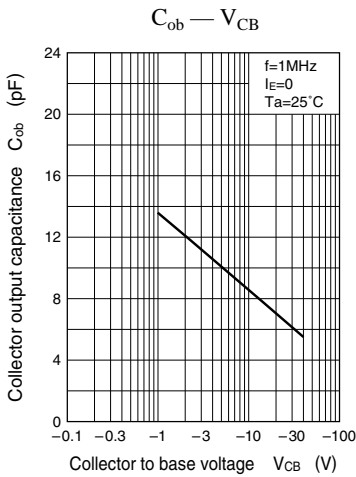


Characteristics charts of UNR1121

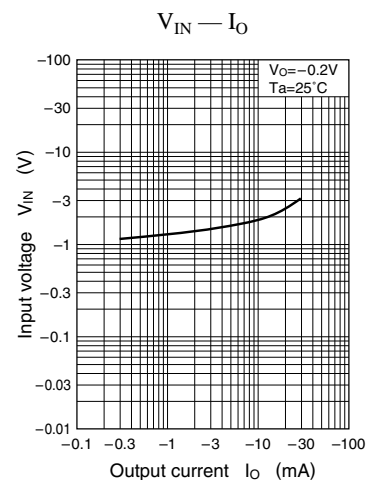
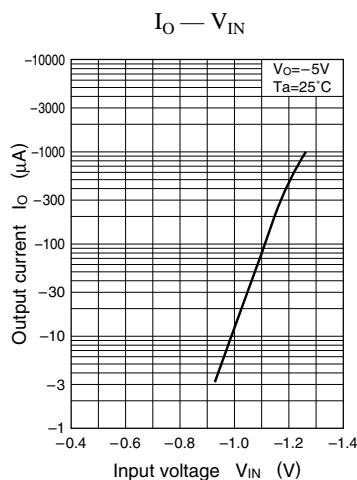
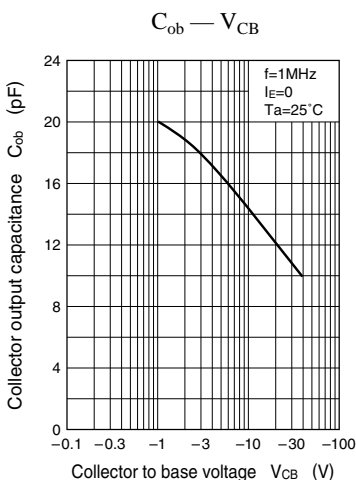
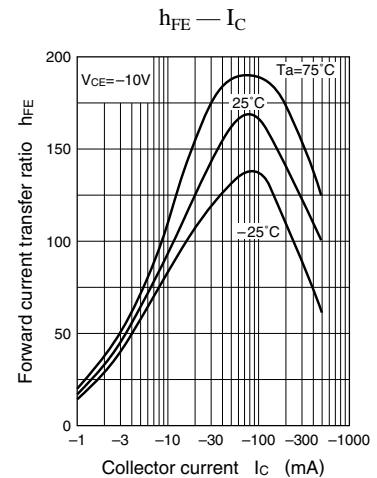
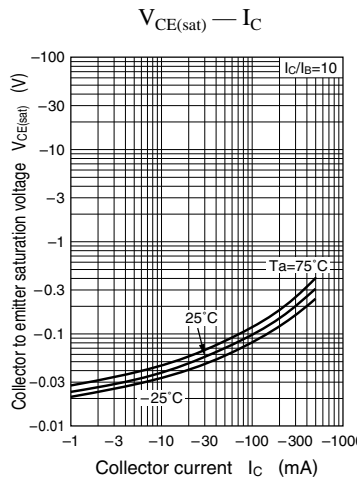
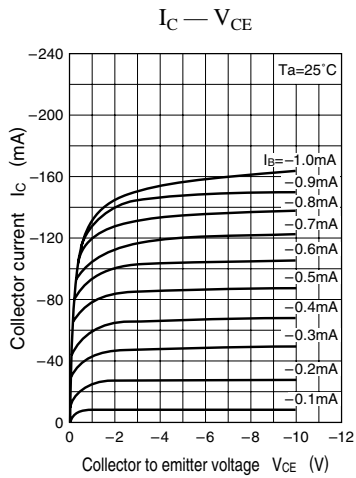


Characteristics charts of UNR1122

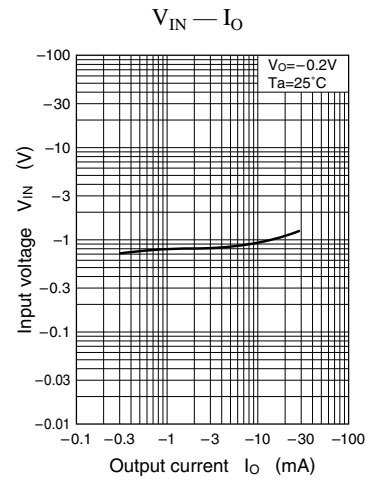
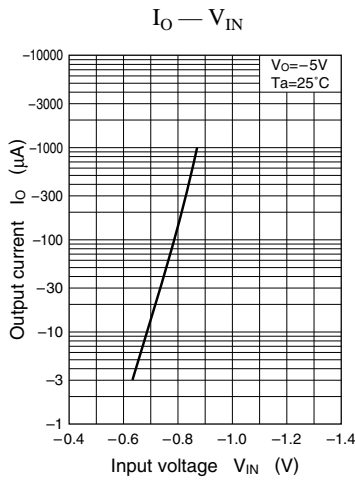
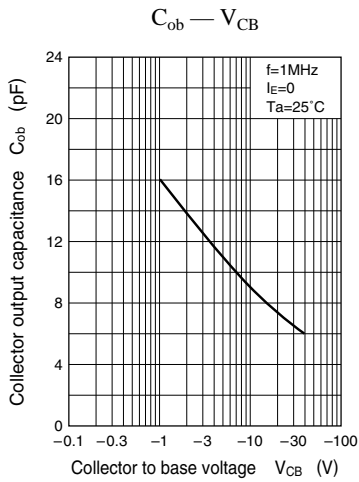
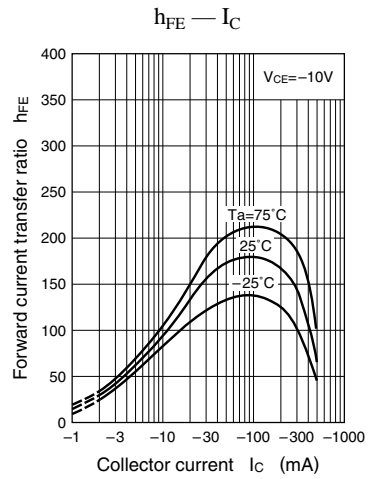
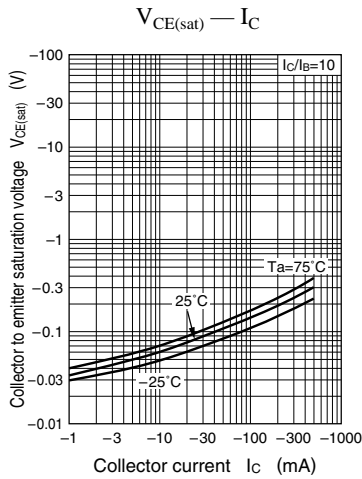
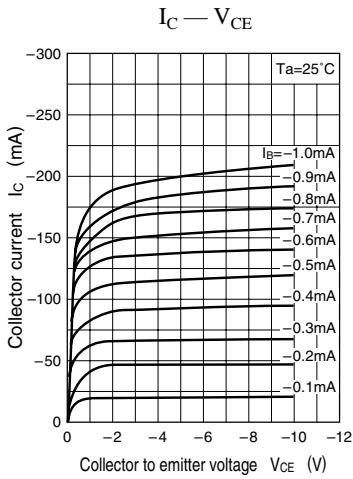




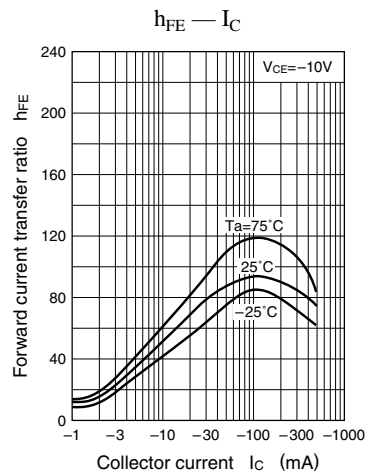
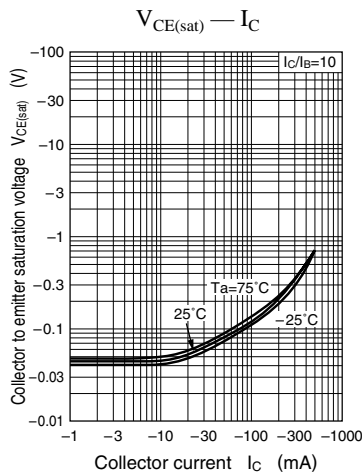
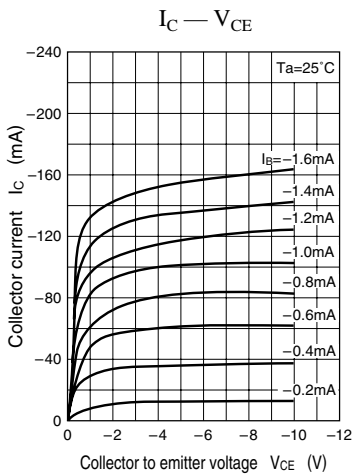
Characteristics charts of UNR1123

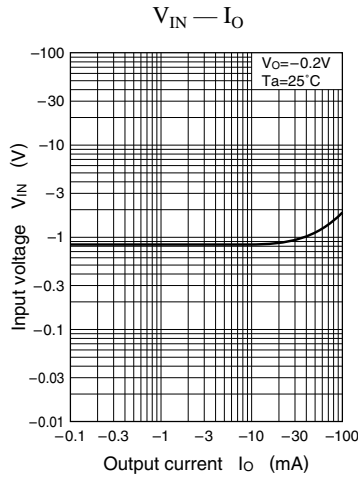
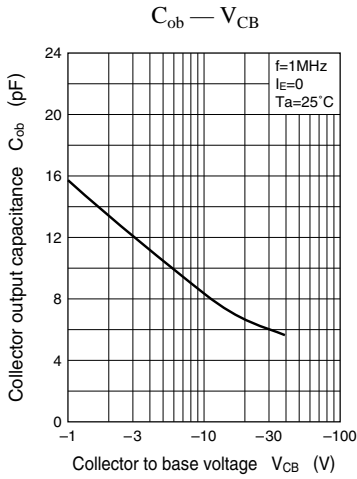


Characteristics charts of UNR1124

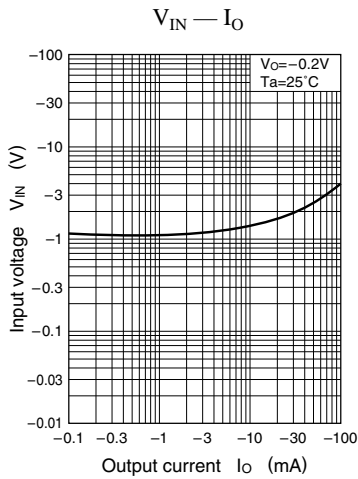
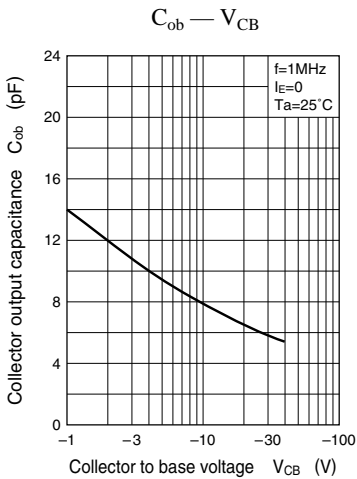
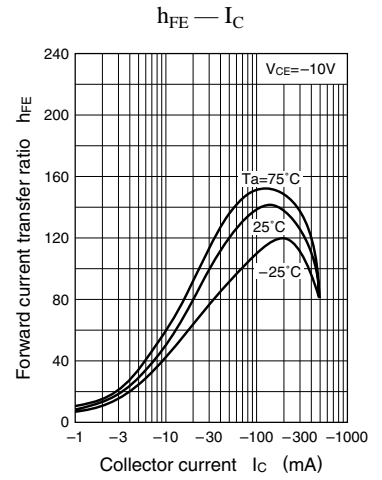
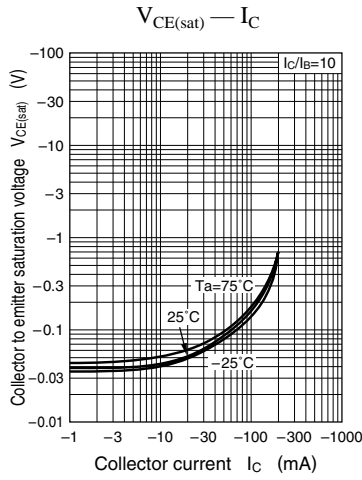
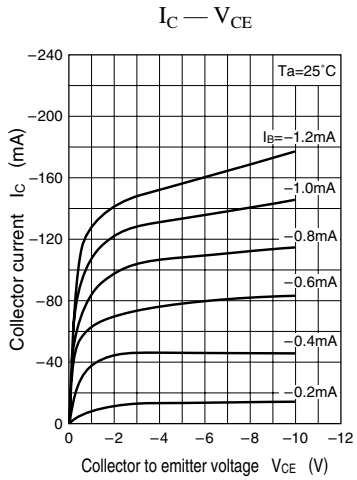


Characteristics charts of UNR112X





Characteristics charts of UNR112Y



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